











TRF37T05

SLWS239A - JUNE 2013-REVISED NOVEMBER 2015

TRF37T05 300-MHz to 4-GHz Quadrature Modulator

Features

- High Linearity:
 - Output IP3: 30 dBm at 1850 MHz
- Low Output Noise Floor: -160 dBm/Hz
- 78-dBc Single-Carrier WCDMA ACPR at -10-dBm Channel Power
- Unadjusted Carrier Suppression: -40 dBm
- Unadjusted Sideband Suppression: -45 dBc
- Single Supply: 3.3-V Operation
- 1-bit Gain Step Control
- Fast Power-Up/Power-Down

Applications

- Cellular Base Station Transmitter
- CDMA: IS95, UMTS, CDMA2000, TD-SCDMA
- LTE (Long Term Evolution), TD-LTE
- TDMA: GSM, EDGE/UWC-136
- Multicarrier GSM (MC-GSM)
- Wireless MAN Wideband Transceivers

3 Description

The TRF37T05 is a low-noise direct quadrature modulator with exceptional TDD performance. It is capable of converting complex modulated signals from baseband or IF directly up to RF. The TRF37T05 is a high-performance, superior-linearity device that is ideal to up-convert to RF frequencies of 300 MHz (Note: appropriate matching network is required for optimal performance at 300 MHz) through 4 GHz. The modulator is implemented as a double-balanced mixer.

The RF output block consists of a differential-tosingle-ended converter that is capable of driving a single-ended 50- Ω load. The TRF37T05 requires a 0.25-V common-mode voltage for optimum linearity performance. The TRF37T05 also provides a fast power-down pin that can be used to reduce power dissipation while maintaining optimized adjusted carrier feed-through performance applications.

The TRF37T05 is available in an RGE-24 VQFN package.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|-----------|-------------------|
| TRF37T05 | VQFN (24) | 4.00 mm x 4.00 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Block Diagram

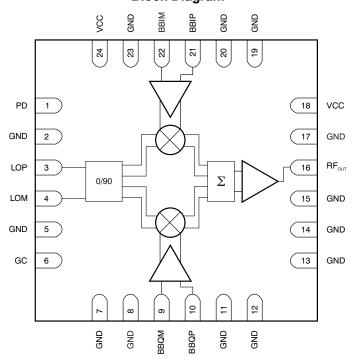




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4 Revision History

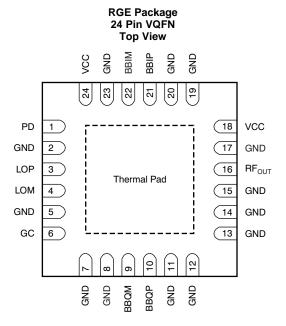
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (June 2013) to Revision A

Page



5 Pin Configuration and Functions



Pin Functions

| | PIN | 1/0 | DESCRIPTION |
|-----|-------------------|-----|---|
| NO. | NAME | I/O | DESCRIPTION |
| 1 | PD | I | Power-down digital input (high = device off) |
| 2 | GND | I | Ground |
| 3 | LOP | I | Local oscillator input |
| 4 | LOM | I | Local oscillator input |
| 5 | GND | I | Ground |
| 6 | GC | I | Gain control digital input (high = high gain) |
| 7 | GND | _ | Ground or leave unconnected |
| 8 | GND | I | Ground |
| 9 | BBQM | I | In-quadrature input |
| 10 | BBQP | I | In-quadrature input |
| 11 | GND | I | Ground |
| 12 | GND | I | Ground |
| 13 | GND | I | Ground |
| 14 | GND | I | Ground |
| 15 | GND | I | Ground |
| 16 | RF _{OUT} | 0 | RF output |
| 17 | GND | I | Ground |
| 18 | VCC | I | Power supply |
| 19 | GND | I | Ground |
| 20 | GND | I | Ground |
| 21 | BBIP | I | In-phase input |
| 22 | BBIM | I | In-phase input |
| 23 | GND | I | Ground |
| 24 | VCC | I | Power supply |



6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

Over operating free-air temperature range (unless otherwise noted).

| | MIN | MAX | UNIT |
|--|------|----------------------|------|
| Supply voltage range (2) | -0.3 | 6 | V |
| Digital I/O voltage range | -0.3 | V _{CC} +0.5 | V |
| Operating virtual junction temperature range, T _J | -40 | 150 | °C |
| Operating ambient temperature range, T _A | -40 | 85 | °C |
| Storage temperature range, T _{stg} | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| | | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1) | ±4000 | |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 (2) | ±250 | V |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. .

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted).

| | | MIN | NOM | MAX | UNIT |
|-----------------|----------------------|------|-----|-----|------|
| V _{CC} | Power-supply voltage | 3.15 | 3.3 | 3.6 | V |

6.4 Thermal Information

| | | TRF37T05 | |
|-------------------------|--|------------|------|
| | THERMAL METRIC | RGE (VQFN) | UNIT |
| | | 24 PINS | |
| θ_{JA} | Junction-to-ambient thermal resistance | 38.4 | °C/W |
| θ_{JCtop} | Junction-to-case (top) thermal resistance | 42.5 | °C/W |
| θ_{JB} | Junction-to-board thermal resistance | 16.6 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 0.9 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 16.6 | °C/W |
| θ_{JCbot} | Junction-to-case (bottom) thermal resistance | 6.6 | °C/W |

⁽²⁾ All voltage values are with respect to network ground terminal.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.5 Electrical Characteristics: General

Over recommended operating conditions; at power supply = 3.3 V and $T_{\Delta} = 25 ^{\circ}\text{C}$, unless otherwise noted.

| | PARAMETERS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------|--------------------------------------|---|-----|------|-----|------|
| DC PAR | AMETERS | | | | | |
| | Total augusts august | T _A = 25°C, device on (PD = low) | | 306 | | mA |
| I _{CC} | Total supply current | T _A = 25°C, device off (PD = high) | | 146 | | mA |
| LO INPU | т | | | | | |
| | LO low frequency | | | 300 | | MHz |
| f_{LO} | LO high frequency | | | 4000 | | MHz |
| | LO input power | | -10 | 0 | +15 | dBm |
| BASEBA | AND INPUTS | | | | | |
| V _{CM} | I and Q input dc common-mode voltage | | | 0.25 | 0.5 | V |
| BW | 1-dB input frequency bandwidth | | | 1000 | | MHz |
| 7 | lanut impadana | Resistance | | 8 | | kΩ |
| Z _I | Input impedance | Parallel capacitance | | 4.6 | | pF |
| POWER | ON/OFF | | | | | |
| | Turn on time | PD = low to 90% final output power | | 0.2 | | μs |
| | Turn off time | PD = high to initial output power -30 dB | | 0.2 | | μs |
| DIGITAL | INTERFACE | | | | | |
| V _{IH} | PD high-level input voltage | | 2 | | | V |
| V _{IL} | PD low-level input voltage | | | | 0.8 | V |



6.6 Electrical Characteristics

Over recommended operating conditions; at power supply = 3.3 V, $T_A = 25^{\circ}\text{C}$, $V_{CM} = 0.25 \text{ V}$; LO Power = 0 dBm, single-ended (LOP); GC set low, V_{IN} BB = 1 V_{PP} (diff) in quadrature, and $f_{BB} = 5.5$ MHz, standard broadband output matching circuit, unless otherwise noted.

| | PARAMETERS | TEST CONDITIONS | MIN TYP MAX | UNIT |
|-------------------------|---------------------------------|---|-------------|--------|
| f _{LO} = 400 N | ИНZ | · | | |
| G | Voltogo gain | Output RMS voltage over input I (or Q) RMS voltage, GC set low | -4.7 | dB |
| G | Voltage gain | Output RMS voltage over input I (or Q) RMS voltage, GC set high | -1.9 | dB |
| D | Outrast | GC set low | -0.7 | dBm |
| P _{OUT} | Output power | GC set high | 2.1 | dBm |
| D4 ID | 0.1.1 | GC set low | 8.5 | dBm |
| P1dB | Output compression point | GC set high | 9.1 | dBm |
| IDO. | 0 + + 100 | $f_{BB1} = 4.5 \text{ MHz}; f_{BB2} = 5.5 \text{ MHz}; GC \text{ set low}$ | 26 | dBm |
| IP3 | Output IP3 | $f_{BB1} = 4.5 \text{ MHz}$; $f_{BB2} = 5.5 \text{ MHz}$; GC set high | 25.4 | dBm |
| | 0 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low | 60.2 | dBm |
| IP2 | Output IP2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high | 61.9 | dBm |
| SBS | Unadjusted sideband suppression | | -57.4 | dBc |
| | | Measured at LO frequency | -51.6 | dBm |
| CF | Unadjusted carrier feedthrough | Measured at 2 x LO | -50 | dBm |
| | | Measured at 3 x LO | -49 | dBm |
| | Output noise floor | DC only to BB inputs; 10-MHz offset from LO | -166.7 | dBm/Hz |
| HD2 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (2 \times f_{BB})$ | -67 | dBc |
| HD3 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (3 \times f_{BB})$ | -64 | dBc |
| f _{LO} = 750 N | ИНZ | | | 1 |
| 0 | V 10 | Output RMS voltage over input I (or Q) RMS voltage, GC set low | 0.2 | dB |
| G | Voltage gain | Output RMS voltage over input I (or Q) RMS voltage, GC set high | 3 | dB |
| D | Output pouce | GC set low | 4.2 | dBm |
| P _{OUT} | Output power | GC set high | 7 | dBm |
| D4 ID | 0.1.1 | GC set low | 13.3 | dBm |
| P1dB | Output compression point | GC set high | 13.9 | dBm |
| IDO. | 0 + + 100 | $f_{BB1} = 4.5 \text{ MHz}; f_{BB2} = 5.5 \text{ MHz}; GC \text{ set low}$ | 31.5 | dBm |
| IP3 | Output IP3 | $f_{BB1} = 4.5 \text{ MHz}$; $f_{BB2} = 5.5 \text{ MHz}$; GC set high | 30.8 | dBm |
| IDO | 0 + + 100 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low | 73.6 | dBm |
| IP2 | Output IP2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high | 80.5 | dBm |
| SBS | Unadjusted sideband suppression | | -45.2 | dBc |
| | | Measured at LO frequency | -45.7 | dBm |
| CF | Unadjusted carrier feedthrough | Measured at 2 x LO | -46 | dBm |
| | | Measured at 3 x LO | -53.5 | dBm |
| | Output noise floor | DC only to BB inputs; 10-MHz offset from LO | -159.9 | dBm/Hz |
| HD2 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (2 \times f_{BB})$ | –70 | dBc |
| HD3 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (3 \times f_{BB})$ | -66 | dBc |



Electrical Characteristics (continued)

Over recommended operating conditions; at power supply = 3.3 V, $T_A = 25$ °C, $V_{CM} = 0.25$ V; LO Power = 0 dBm, single-ended (LOP); GC set low, V_{IN} BB = 1 V_{PP} (diff) in quadrature, and $f_{BB} = 5.5$ MHz, standard broadband output matching circuit, unless otherwise noted.

| | PARAMETERS | TEST CONDITIONS | MIN TYP N | IAX UNIT |
|-------------------------|---------------------------------|--|-----------|----------|
| f _{LO} = 900 N | ЛНz | | | |
| G | Voltago gain | Output RMS voltage over input I (or Q) RMS voltage, GC set low | 0.3 | dB |
| G | Voltage gain | Output RMS voltage over input I (or Q) RMS voltage, GC set high | 3.1 | dB |
| D | Output nouse | GC set low | 4.3 | dBm |
| P _{OUT} | Output power | GC set high | 7.1 | dBm |
| חו אף | Output compression point | GC set low | 13.2 | dBm |
| P1dB | Output compression point | GC set high | 13.7 | dBm |
| IP3 | Output IP2 | f_{BB1} = 4.5 MHz; f_{BB2} = 5.5 MHz; GC set low | 31.7 | dBm |
| 1173 | Output IP3 | f_{BB1} = 4.5 MHz; f_{BB2} = 5.5 MHz; GC set high | 30.9 | dBm |
| IDO. | Quitavit ID2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low | 71.5 | dBm |
| IP2 | Output IP2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high | 75.3 | dBm |
| SBS | Unadjusted sideband suppression | | -43.8 | dBc |
| | | Measured at LO frequency | -48.5 | dBm |
| CF | Unadjusted carrier feedthrough | Measured at 2 x LO | -53 | dBm |
| | | Measured at 3 x LO | -50 | dBm |
| | Output noise floor | DC only to BB inputs; 10-MHz offset from LO | -157.9 | dBm/Hz |
| HD2 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f_{LO} $\pm (2 \times f_{BB})$ | -80 | dBc |
| HD3 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f_{LO} $\pm (3 \text{ x f}_{BB})$ | -65 | dBc |
| f _{LO} = 1840 | MHz | | | |
| 0 | Voltage gain | Output RMS voltage over input I (or Q) RMS voltage, GC set low | -0.1 | dB |
| G | | Output RMS voltage over input I (or Q) RMS voltage, GC set high | 2.5 | dB |
| n | Output nouse | GC set low | 3.9 | dBm |
| Роит | Output power | GC set high | 6.5 | dBm |
| חו אף | Output compression point | GC set low | 13.2 | dBm |
| P1dB | Output compression point | GC set high | 13.6 | dBm |
| IP3 | Output IP3 | f_{BB1} = 4.5 MHz; f_{BB2} = 5.5 MHz; GC set low | 32.1 | dBm |
| iro | Output IF3 | f_{BB1} = 4.5 MHz; f_{BB2} = 5.5 MHz; GC set high | 30.3 | dBm |
| IP2 | Output IP2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low | 60.8 | dBm |
| IFZ | Output IF2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high | 62 | dBm |
| SBS | Unadjusted sideband suppression | | -43.4 | dBc |
| | | Measured at LO frequency | -42.4 | dBm |
| CF | Unadjusted carrier feedthrough | Measured at 2 x LO | -41 | dBm |
| | | Measured at 3 x LO | -53 | dBm |
| | Output noise floor | DC only to BB inputs; 10-MHz offset from LO | -158.8 | dBm/Hz |
| HD2 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (2 \times f_{BB})$ | -69 | dBc |
| HD3 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (3 \times f_{BB})$ | -80 | dBc |



Electrical Characteristics (continued)

Over recommended operating conditions; at power supply = 3.3 V, $T_A = 25$ °C, $V_{CM} = 0.25$ V; LO Power = 0 dBm, single-ended (LOP); GC set low, V_{IN} BB = 1 V_{PP} (diff) in quadrature, and $f_{BB} = 5.5$ MHz, standard broadband output matching circuit, unless otherwise noted.

| | PARAMETERS | TEST CONDITIONS | MIN TYP | MAX UNIT |
|------------------------|---------------------------------|---|-------------|----------|
| f _{LO} = 2140 | MHz | | | |
| G | Voltago goin | Output RMS voltage over input I (or Q) RMS voltage, GC set low | 0.1 | dB |
| G | Voltage gain | Output RMS voltage over input I (or Q) RMS voltage, GC set high | 2.9 | dB |
| D | Output power | GC set low | 4.1 | dBm |
| P _{OUT} | Output power | GC set high | 6.9 | dBm |
| חואם | Output compression point | GC set low | 13.1 | dBm |
| P1dB | Output compression point | GC set high | 13.5 | dBm |
| ID2 | Output IP2 | $f_{BB1} = 4.5 \text{ MHz}$; $f_{BB2} = 5.5 \text{ MHz}$; GC set low | 28.6 | dBm |
| IP3 | Output IP3 | $f_{BB1} = 4.5 \text{ MHz}$; $f_{BB2} = 5.5 \text{ MHz}$; GC set high | 27.6 | dBm |
| IDO. | Output IP2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low | 65.5 | dBm |
| IP2 | Output IP2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high | 68.2 | dBm |
| SBS | Unadjusted sideband suppression | | -45.6 | dBc |
| | | Measured at LO frequency | -39.3 | dBm |
| CF | Unadjusted carrier feedthrough | Measured at 2 x LO | -37 | dBm |
| | | Measured at 3 x LO | -46 | dBm |
| | Output noise floor | DC only to BB inputs; 10-MHz offset from LO | -160.0 | dBm/Hz |
| HD2 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (2 \times f_{BB})$ | -61 | dBc |
| HD3 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f_{LO} $\pm (3 \times f_{BB})$ | -60 | dBc |
| f _{LO} = 2600 | MHz | , | | ' |
| 0 | | Output RMS voltage over input I (or Q) RMS voltage, GC set low | -0.8 | dB |
| G | Voltage gain | Output RMS voltage over input I (or Q) RMS voltage, GC set high | 2 | dB |
| n | Output nouse | GC set low | 3.2 | dBm |
| Роит | Output power | GC set high | 5.6 | dBm |
| D4 4D | Output compression point | GC set low | 12.5 | dBm |
| P1dB | Output compression point | GC set high | 12.8 | dBm |
| ID2 | Output IP2 | $f_{BB1} = 4.5 \text{ MHz}$; $f_{BB2} = 5.5 \text{ MHz}$; GC set low | 28 | dBm |
| IP3 | Output IP3 | Ff _{BB1} = 4.5 MHz; f _{BB2} = 5.5 MHz; GC set high | 27.2 | dBm |
| IDO | Output IDO | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low | 67.9 | dBm |
| IP2 | Output IP2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high | 66.4 | dBm |
| SBS | Unadjusted sideband suppression | | -52.9 | dBm |
| | | Measured at LO frequency | -37.8 | dBm |
| CF | Unadjusted carrier feedthrough | Measured at 2 x LO | -41 | dBm |
| | | Measured at 3 x LO | -42 | dBm |
| | Output noise floor | DC only to BB inputs; 10-MHz offset from LO | -160.6 | dBm/Hz |
| HD2 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f_{LO} $\pm (2 \times f_{BB})$ | -67 | dBc |
| HD3 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (3 \times f_{BB})$ | – 59 | dBc |

Product Folder Links: TRF37T05

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Electrical Characteristics (continued)

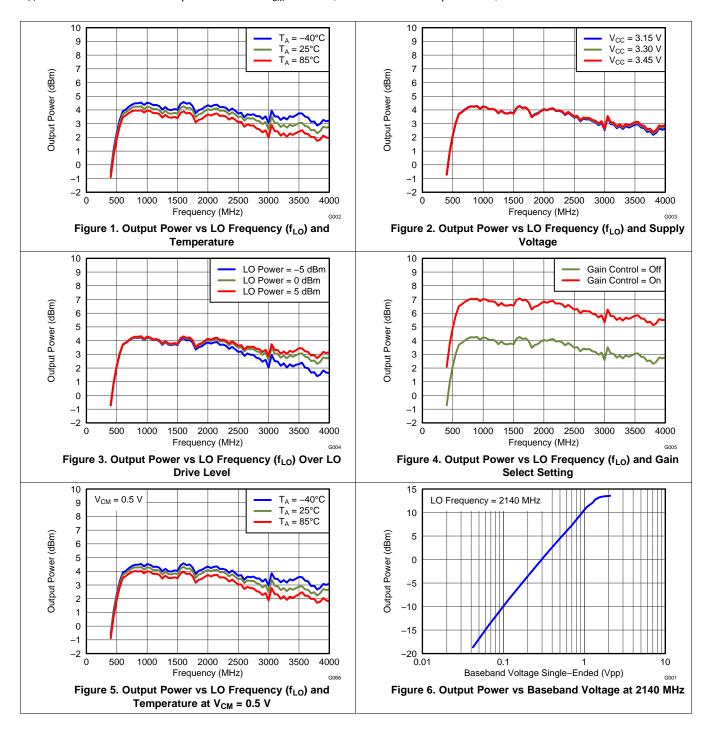
Over recommended operating conditions; at power supply = 3.3 V, $T_A = 25$ °C, $V_{CM} = 0.25$ V; LO Power = 0 dBm, single-ended (LOP); GC set low, V_{IN} BB = 1 V_{PP} (diff) in quadrature, and $f_{BB} = 5.5$ MHz, standard broadband output matching circuit, unless otherwise noted.

| | PARAMETERS | TEST CONDITIONS | MIN TYP | MAX | UNIT |
|------------------------|---------------------------------|---|---------|-----|--------|
| f _{LO} = 3500 |) MHz | | | • | |
| 0 | Valtaga gain | Output RMS voltage over input I (or Q) RMS voltage, GC set low | -1 | | dB |
| G | Voltage gain | Output RMS voltage over input I (or Q) RMS voltage, GC set high | 1.8 | | dB |
| P _{OUT} | Output news | GC set low | 3 | | dBm |
| Pout | Output power | GC set high | 5.8 | | dBm |
| P1dB | Output compression point | GC set low | 12.1 | | dBm |
| PIUB | Output compression point | GC set high | 12.3 | | dBm |
| IP3 | Output IP3 | f_{BB1} = 4.5 MHz; f_{BB2} = 5.5 MHz; GC set low | 23.8 | | dBm |
| IP3 | | f_{BB1} = 4.5 MHz; f_{BB2} = 5.5 MHz; GC set high | 25.3 | | dBm |
| IP2 | Output IP2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set low | 47.8 | | dBm |
| IF2 | Output IF2 | Measured at f _{LO} + (f _{BB1} ± f _{BB2}), GC set high | 48.6 | | dBm |
| SBS | Unadjusted sideband suppression | | -45.2 | | dBm |
| | | Measured at LO frequency | -31.6 | | dBm |
| CF | Unadjusted carrier feedthrough | Measured at 2 x LO | -30 | | dBm |
| | | Measured at 3 x LO | -53 | | dBm |
| | Output noise floor | DC only to BB inputs; 10-MHz offset from LO | -160.6 | | dBm/Hz |
| HD2 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at $f_{LO} \pm (2 \times f_{BB})$ | -54 | | dBc |
| HD3 _{BB} | Baseband harmonics | Measured with ± 1 -MHz tone at 0.5 V _{PP} each at f_{LO} $\pm (3 \times f_{BB})$ | -50 | | dBc |



6.7 Typical Characteristics: Single-Tone Baseband

 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 5.5 MHz; baseband I/Q amplitude = 1-V_{PP} differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.

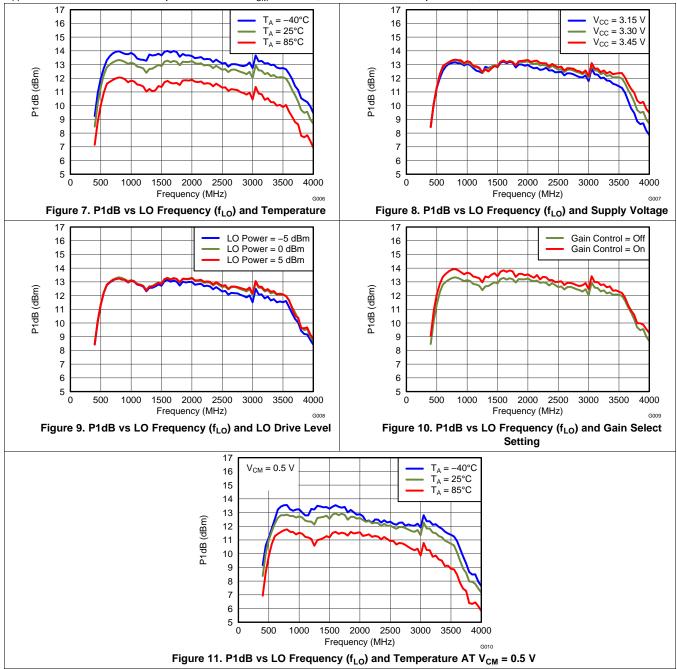


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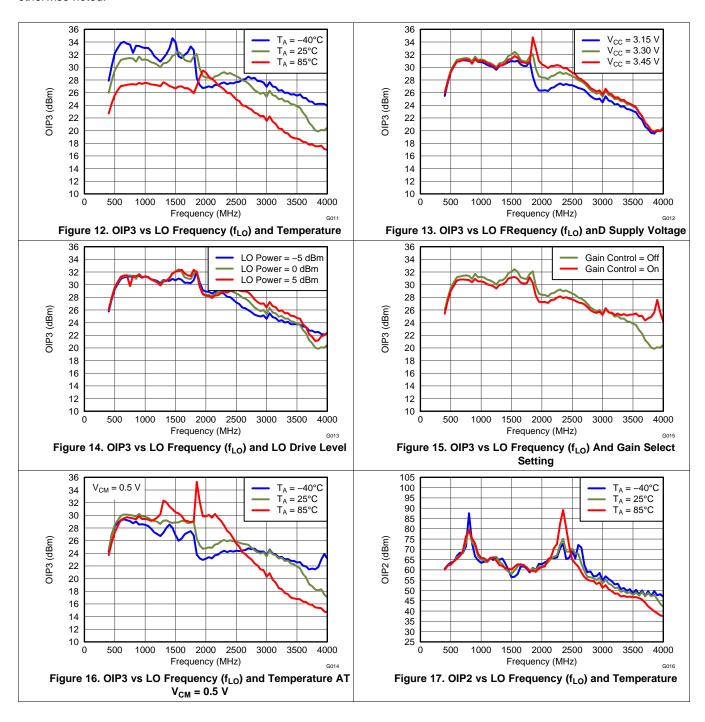
 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 5.5 MHz; baseband I/Q amplitude = 1-V_{PP} differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.





6.8 Typical Characteristics: Two-Tone Baseband

 $V_{CC} = 3.3 \text{ V}$; $T_A = 25^{\circ}\text{C}$; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with $V_{CM} = 0.25 \text{ V}$; and broadband output match, unless otherwise noted.

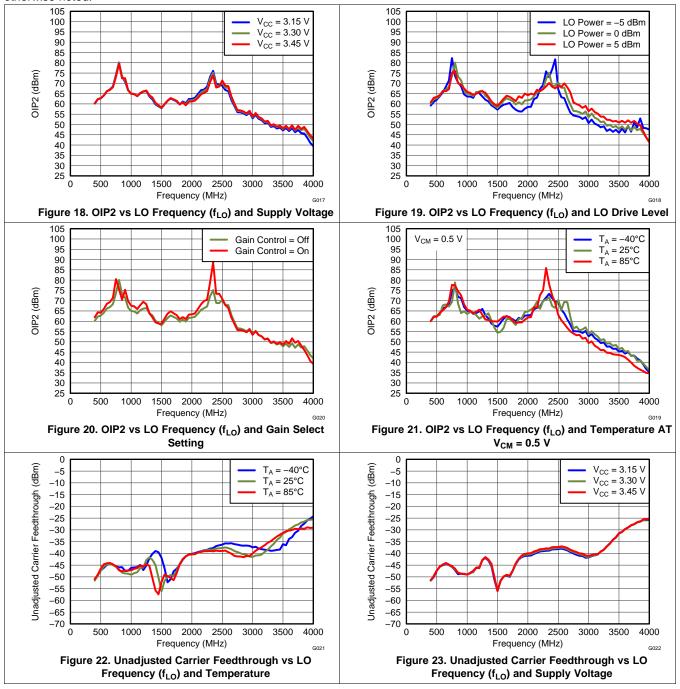


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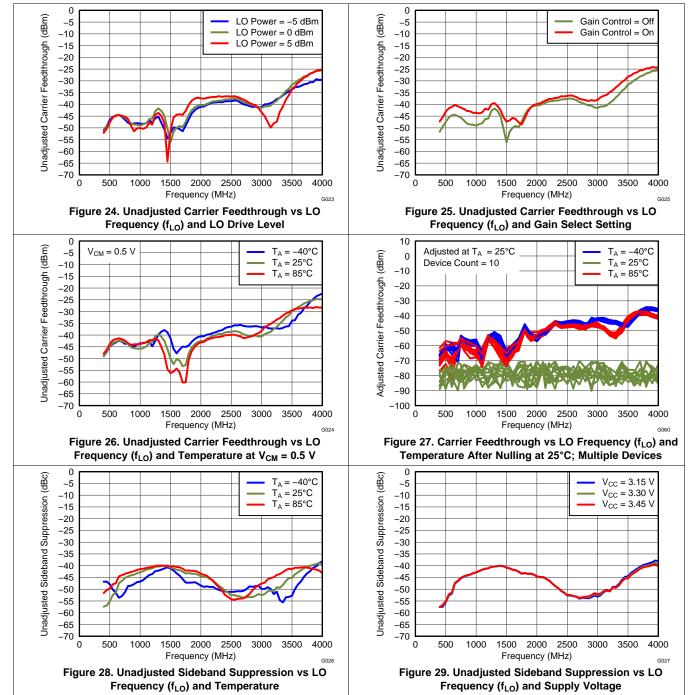


 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.





 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.



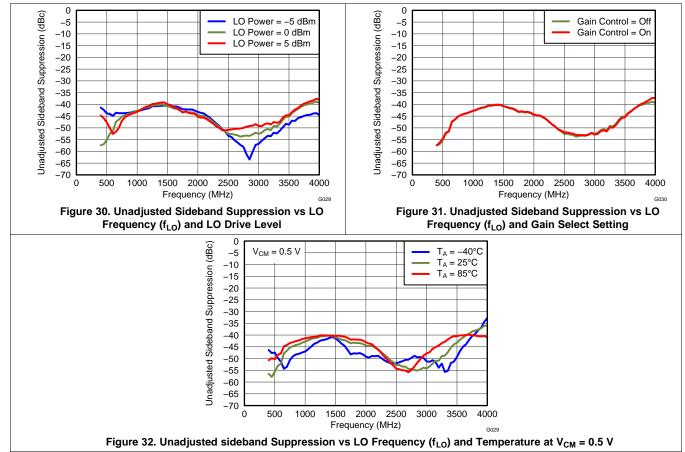
Product Folder Links: TRF37T05

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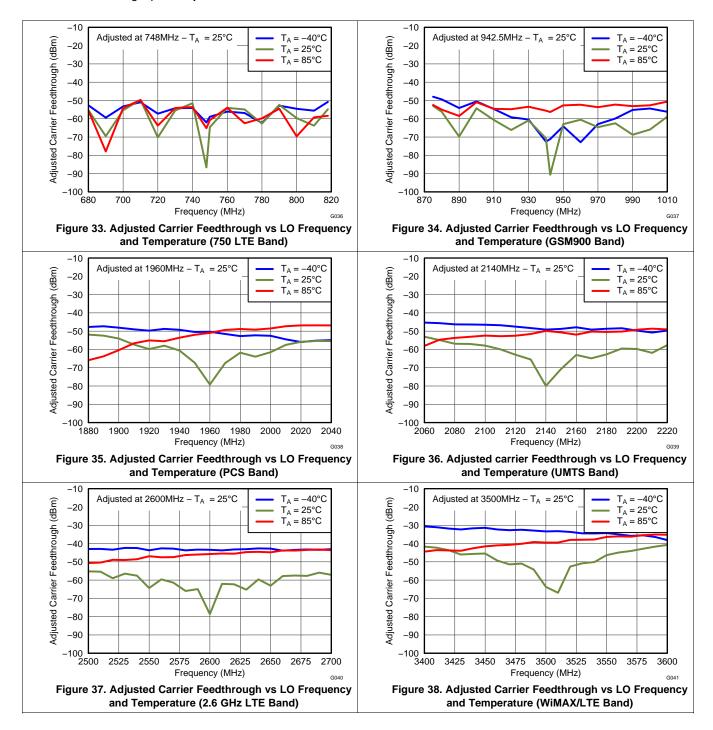
 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.





6.9 Typical Characteristics: Two-Tone Baseband, Mid-Band Calibration

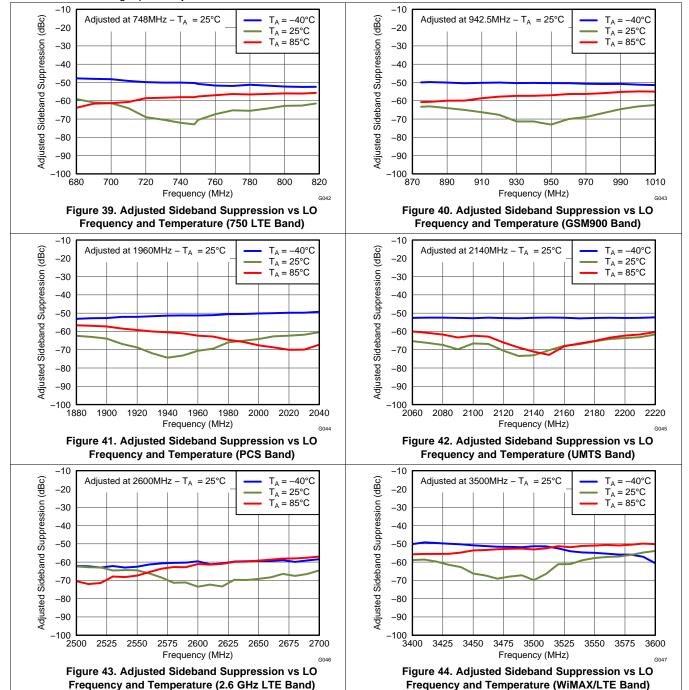
 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted. Single point adjustment mid-band.





Typical Characteristics: Two-Tone Baseband, Mid-Band Calibration (continued)

 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted. Single point adjustment mid-band.

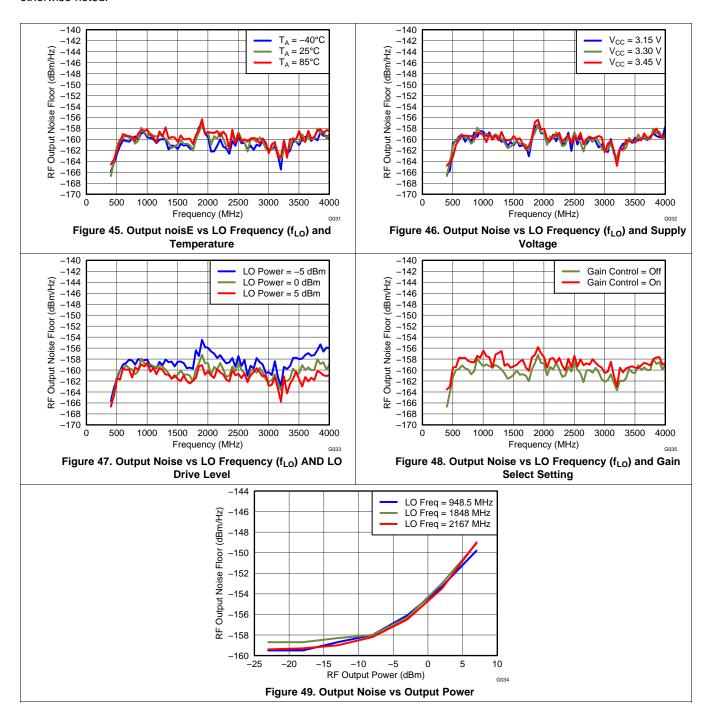


Product Folder Links: TRF37T05



6.10 Typical Characteristics: No Baseband

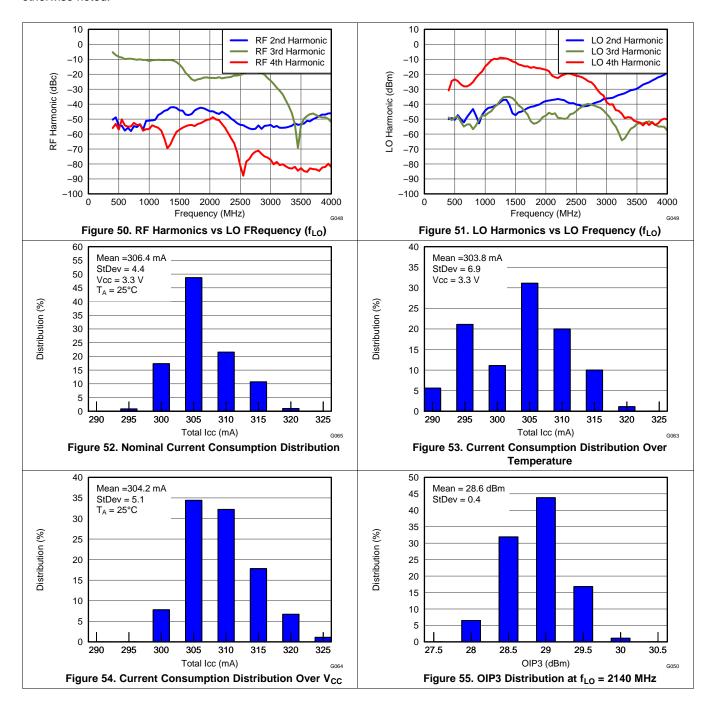
 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); and input baseband ports terminated in 50 Ω , unless otherwise noted.





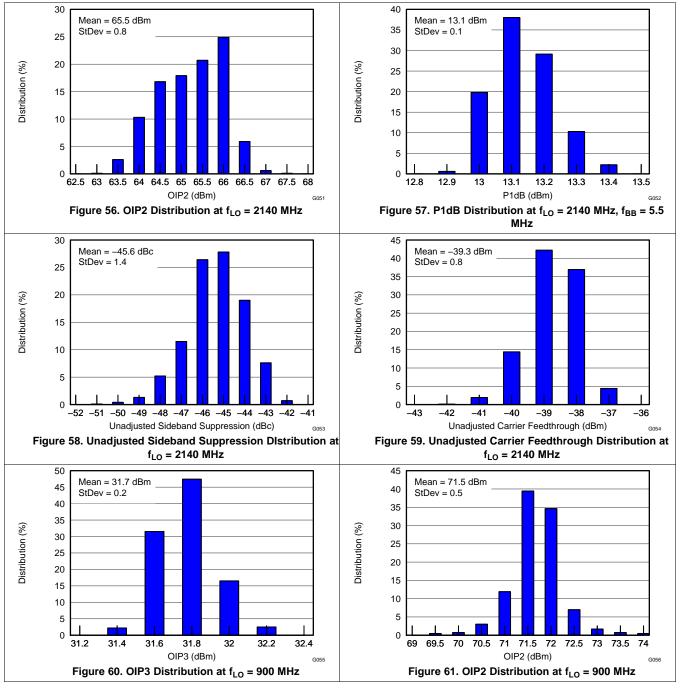
6.11 Typical Characteristics: Two-Tone Baseband

 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.





 V_{CC} = 3.3 V; T_A = 25°C; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5-V_{PP}/tone differential sine waves in quadrature with V_{CM} = 0.25 V; and broadband output match, unless otherwise noted.

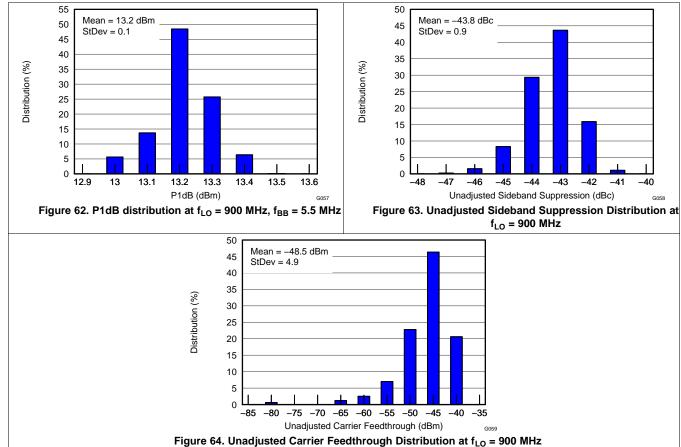


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 $V_{CC} = 3.3 \text{ V}$; $T_A = 25^{\circ}\text{C}$; LO = 0 dBm, single-ended drive (LOP); I/Q frequency (f_{BB}) = 4.5 MHz, 5.5 MHz; baseband I/Q amplitude = 0.5- V_{PP} /tone differential sine waves in quadrature with $V_{CM} = 0.25 \text{ V}$; and broadband output match, unless otherwise noted.



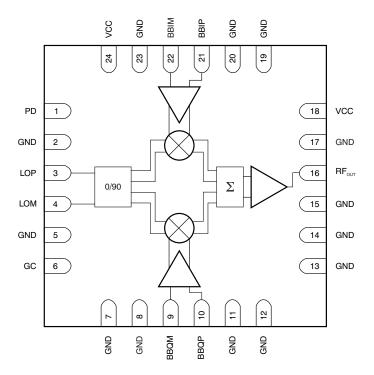


7 Detailed Description

7.1 Overview

TRF37T05 is a low-noise direct quadrature modulator with high linearity, capable of converting complex modulated signals from baseband or IF directly to RF. With high-performance and superior-linearity , TRF37T05 is an ideal device to up-convert to RF frequencies of 300 MHz through 4 GHz. With appropriate matching network, optimal performance can be obtained. The modulator is implemented as a double-balanced mixer. TRF37T05 has a RF output block which consists of a differential-to-single-ended converter that is capable of directly driving a single-ended 50- Ω load. The TRF37T05 requires a 0.25-V common-mode voltage for optimal linearity performance. With a fast power-down pin, TRF37T05 can be used to reduce power dissipation in TDD application while maintaining optimized adjusted carrier feed-through performance. TRF37T05 is available in an REG-24 VQFN package.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Gain Control Feature

TRF37T05 has a specific GC pin which is used for gain control. The GC pin is gain control digital input which is internally pulled down. When driving low or left open, modulator is in low gain mode. With driving high externally, the modulator is in high gain mode. This 1 bit gain step control feature offers a typical 3-dB gain increase in high gain mode. If power optimization is desired, driving this pin low can easily put the modulator into low gain mode.

7.4 Device Functional Modes

7.4.1 Power Down Mode

TRF37T05 features a PD pin to power down the modulator. The PD pin is internally pulled down. When the power-down digital input pin is driven high, the RF output buffer is off. This feature provides a fast power-down which can be used to reduce power dissipation in time division duplexing applications while maintaining optimized adjusted carrier feed-through performance.



8 Application and Implementation

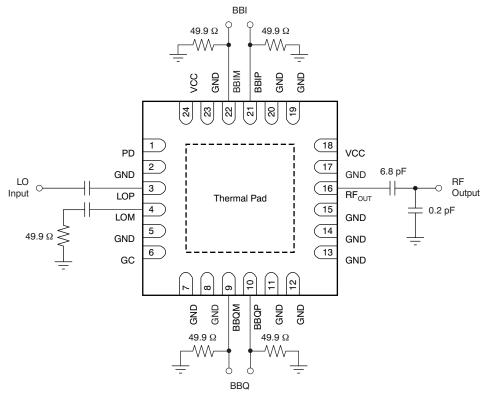
NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

TRF37T05 is a quadrature modulator for up-converting the in-phase (I) and the quadrature-phase (Q) signals to radio frequency (RF) in the transmit chain. Typically, the device is used between the digital-to-analog converter (DAC) and the RF power amplifier.

8.2 Typical Application



(1) Pin 1 (PD) and Pin 6 (GC) are internally pulled down.

Figure 65. Typical Application Circuit



Typical Application (continued)

8.2.1 Design Requirements

For this design example, use the parameters shown in Table 1.

Table 1. Pin Termination Requirements and Limitations

| NAME | PIN NO | DESCRIPTION |
|-------|--------|--|
| BBQM | 9 | Base-band in-quadrature input: negative terminal. Input impedance is 8 K Ω //4.6 pF. Optimal linearity is obtained if V _{CM} is 0.25 V. Normally terminated in 50 Ω |
| BBQP | 10 | Base-band in-quadrature input: positive terminal. Input impedance is 8 K Ω //4.6 pF. Optimal linearity is obtained if V _{CM} is 0.25 V. Normally terminated in 50 Ω |
| LOP | 3 | Local oscillator input: positive terminal. This is preferred port when driving single ended. Normally AC coupled and terminated in 50 Ω |
| LOM | 4 | Local oscillator input: negative terminal. When driving LO single-ended, normally AC coupled and terminated in 50 Ω . |
| RFOUT | 16 | RF output. Normally using optimal matching circuits to match RF output to 50 Ω. Normally AC coupled. |
| GC | 6 | Gain control digital input. Internally pulled down. When driving high, get 3 dB gain increase of RF output. |
| PD | 1 | Power down digital input. Internally pulled down. When driving high, the modulator is off. |
| VCC | 18,24 | 3.3-V power supply. Can be tied together and source from a single clean supply. Each pin should be properly RF bypassed and decoupled. |

8.2.2 Detailed Design Procedure

8.2.2.1 Baseband Inputs

The baseband inputs consist of the in-phase signal (I) and the Quadrature-phase signal (Q). The I and Q lines are differential lines that are driven in quadrature. The nominal drive level is $1-V_{PP}$ differential on each branch.

The baseband lines are nominally biased at 0.25-V common-mode voltage (V_{CM}); however, the device can operate with a V_{CM} in the range of 0 V to 0.5 V. The baseband input lines are normally terminated in 50 Ω , though it is possible to modify this value if necessary to match to an external filter load impedance requirement.

8.2.2.2 LO Input

The LO inputs can be driven either single-ended or differentially. There is no significant performance difference between either option with the exception of the sideband suppression. If driven single-ended, either input can be used, but LOP (pin 3) is recommended for best broadband performance of sideband suppression. When driving in single-ended configuration, simply ac-couple the unused port and terminate in 50 Ω . The comparison of the sideband suppression performance is shown in Figure 71 for driving the LO single-ended from either pin and for driving the LO input differentially.

8.2.2.3 RF Output

The RF output must be ac-coupled and can drive a $50-\Omega$ load. The suggested output match provides the best broadband performance across the frequency range of the device. It is possible to modify the output match to optimize performance within a selected band if needed. The optimized matching circuits are to match the RF output impedances to $50~\Omega$.

Figure 72 shows a slightly better OIP3 performance at the frequency above 1850 MHz with an 0.2-pF matching capacitor.



8.2.2.4 350-MHz Operation

A different matching circuit, as shown in Figure 66, could also be applied to improve the performance for the frequency from 300 MHz to 400 MHz.

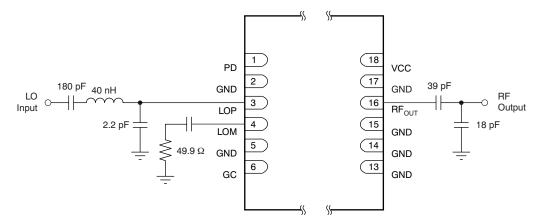


Figure 66. Matching Components for Operation Centered at 350 MHz

Figure 73 and Figure 74 show a slight improvement in OIP3 performance at frequencies above 1850 MHz with an 0.2-pF matching capacitor.

8.2.2.5 DAC to Modulator Interface Network

For optimum linearity and dynamic range, a digital-to-analog converter (DAC) can interface directly with the TRF37T05 modulator. It is imperative that the common-mode voltage of the DAC and the modulator baseband inputs be properly maintained. With the proper interface network, the common-mode voltage of the DAC can be translated to the proper common-mode voltage of the modulator. The TRF37T05 common-mode voltage is typically 0.25 V, and is ideally suited to interface with the DAC3482/3484 (DAC348x) family because the common-mode voltages of both devices are the same; there is no translation network required. The interface network is shown in Figure 67.

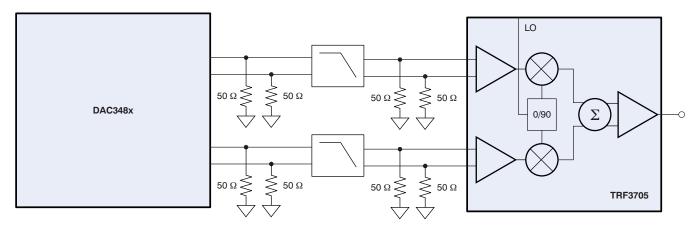


Figure 67. DAC348x Interface with the TRF37T05 Modulator

The DAC348x requires a load resistor of 25 Ω per branch to maintain its optimum voltage swing of 1-V_{PP} differential with a 20-mA max current setting. The load of the DAC is separated into two parallel 50- Ω resistors placed on the input and output side of the low-pass filter. This configuration provides the proper resistive load to the DAC while also providing a convenient 50- Ω source and load termination for the filter.



8.2.2.6 DAC348x with TRF37T05 Modulator Performance

The combination of the DAC348x driving the TRF37T05 modulator yields excellent system parameters suitable for high-performance applications. As an example, the following sections illustrate the typical modulated adjacent channel power ratio (ACPR) for common telecom standards and bands. These measurements were taken on the DAC348x evaluation board.

8.2.2.6.1 WCDMA

The adjacent channel power ratio (ACPR) performance using a single-carrier WCDMA signal in the UMTS band is shown in Figure 68.

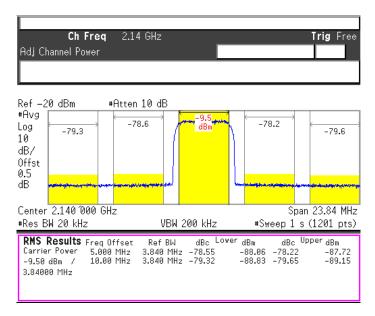


Figure 68. Single-Carrier WCDMA ACPR, IF = 30 MHz, LO Frequency = 2110 MHz

A marginal improvement in OIP3 and output noise performance can be observed by increasing the LO drive power, resulting in slightly improved ACPR performance. The ACPR performance versus LO drive level is plotted in Figure 75 across common frequencies to illustrate the amount of improvement that is possible.



8.2.2.6.2 LTE

ACPR performance using a 10 MHz LTE signal in the 700-MHz band is shown in Figure 69.

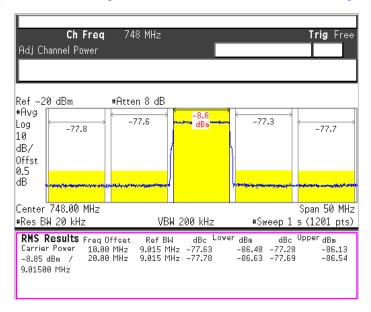


Figure 69. 10 MHz LTE ACPR, IF = 30 MHz, LO Frequency = 718 MHz

8.2.2.6.3 MC-GSM

ACPR performance using a four-carrier MC-GSM signal in the 1800-MHz band is shown in Figure 70.

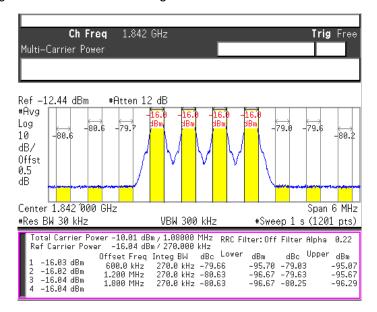
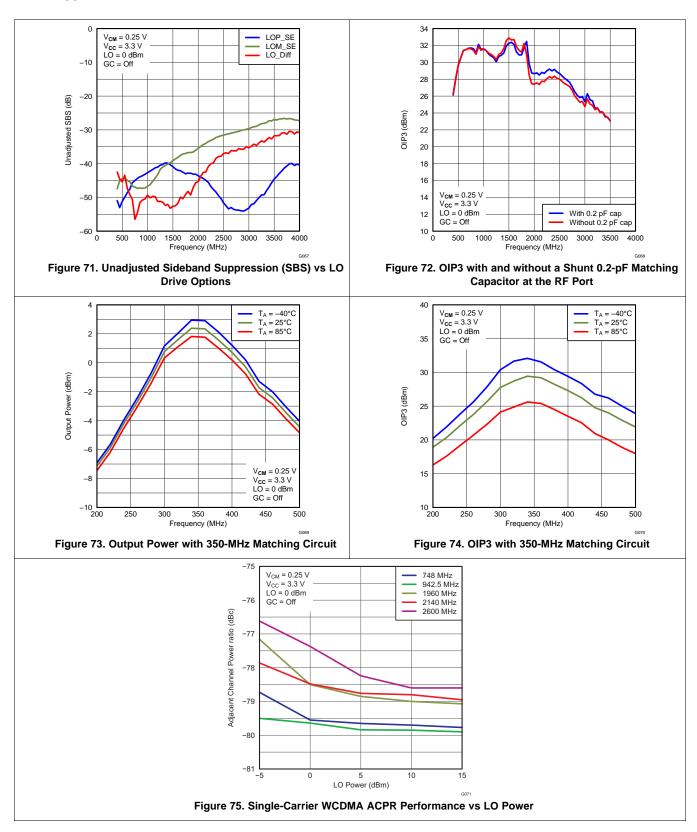


Figure 70. Four-Carrier MC-GSM, IF = 30 MHz ACPR, LO Frequency = 1812 MHz

TEXAS INSTRUMENTS

8.2.3 Application Curves





9 Power Supply Recommendations

The TRF37T05 is powered by supplying a nominal 3.3 V to pins 18 and 24. These supplies can be tied together and sourced from a single clean supply. Proper RF bypassing should be placed close to each power supply pin.

Ground pin connections should have at least one ground via close to each ground pin to minimize ground inductance. The PowerPADTM must be tied to ground, preferably with the recommended ground via pattern to provide a good thermal conduction path to the alternate side of the board and to provide a good RF ground for the device. (Refer to *Layout Guidelines* for additional information.)



10 Layout

Populated RoHS-compliant evaluation boards are available for testing the TRF37T05 as a stand-alone device. Contact your local TI representative for information on ordering these evaluation modules, or see the TRF37T05 product folder on the TI website. In addition, the TRF37T05 can be evaluated with the DAC348x (quad/dual 16-bit, 1.25GSPS) EVM driving the baseband inputs through a seamless interface at 0.25V common-mode voltage.

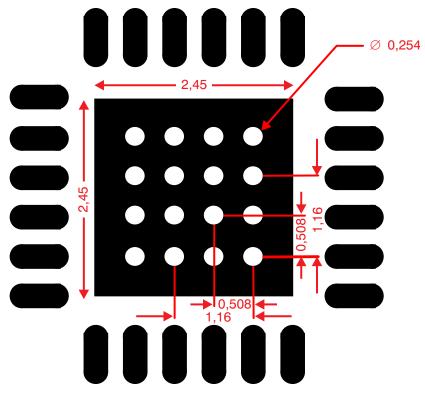
10.1 Layout Guidelines

The TRF37T05 device is fitted with a ground slug on the back of the package that must be soldered to the printed circuit board (PCB) ground with adequate ground vias to ensure a good thermal and electrical connection. The recommended via pattern and ground pad dimensions are shown in Figure 76. The recommended via diameter is 10 mils (0.10 in or 0,25 mm). The ground pins of the device can be directly tied to the ground slug pad for a low-inductance path to ground. Additional ground vias may be added if space allows.

Decoupling capacitors at each of the supply pins are strongly recommended. The value of these capacitors should be chosen to provide a low-impedance RF path to ground at the frequency of operation. Typically, the value of these capacitors is approximately 10 pF or lower.

The device exhibits symmetry with respect to the quadrature input paths. It is recommended that the PCB layout maintain this symmetry in order to ensure that the quadrature balance of the device is not impaired. The I/Q input traces should be routed as differential pairs and the respective lengths all kept equal to each other. On the RF traces, maintain proper trace widths to keep the characteristic impedance of the RF traces at a nominal 50 Ω .

10.2 Layout Example



Note: Dimensions are in millimeters (mm).

Figure 76. PCB Ground Via Layout Guide



11 Device and Documentation Support

11.1 Device Support

11.1.1 Definition of Specifications

11.1.1.1 Carrier Feedthrough

This specification measures the power of the local oscillator component that is present at the output spectrum of the modulator. The performance depends on the dc offset balance within the baseband input lines. Ideally, if all of the baseband lines were perfectly matched, the carrier (that is, the LO) would be naturally suppressed; however, small dc offset imbalances within the device allow some of the LO component to feed through to the output. This parameter is expressed as an absolute power in dBm, and is independent of the RF output power and the injected LO input power.

It is possible to adjust the baseband dc offset balance to suppress the output carrier component. Devices such as the DAC348x DAC family have dc offset adjustment capabilities specifically for this function. The Adjusted Carrier Feedthrough graphs (see Figure 33 through Figure 38) optimize the performance at the center of the band at room temperature. Then, with the adjusted dc offset values held constant, the parameter is measured over the frequency band and across the temperature extremes. The typical performance plots provide an indication of how well the adjusted carrier suppression can be maintained over frequency and temperature with only one calibration point.

11.1.1.2 Sideband Suppression

This specification measures the suppression of the undesired sideband at the output of the modulator relative to the desired sideband. If the amplitude and phase within the I and Q branch of the modulator were perfectly matched, the undesired sideband (or image) would be naturally suppressed. Amplitude and phase imbalance in the I and Q branches result in the increase of the undesired sideband. This parameter is measured in dBc relative to the desired sideband.

It is possible to adjust the relative amplitude and phase balance within the baseband lines to suppress the unwanted sideband. Devices such as the DAC348x DAC family have amplitude and phase adjustment control specifically for this function. The Adjusted Sideband Suppression graphs (refer to Figure 39 through Figure 44) optimize the performance at the center of the band at room temperature. Then, with the adjusted amplitude and phase values held constant, the parameter is measured over the frequency band and across the temperature extremes. The performance plots provide an indication of how well the adjusted sideband suppression can be maintained over frequency and temperature with only one calibration point.

11.1.1.3 Output Noise

The output noise specifies the absolute noise power density that is output from the RF_{OUT} pin (pin 16). This parameter is expressed in dBm/Hz. This parameter, in conjunction with the OIP3 specification, indicates the dynamic range of the device. In general, at high output signal levels the performance is limited by the linearity of the device; at low output levels, on the other hand, the performance is limited by noise. As a result of the higher gain and output power of the TRF3705 compared to earlier devices, it is expected that the noise density is slightly higher as well. With its increased gain and high OIP3 performance, the overall dynamic range of the TRF3705 is maintained at exceptional levels.

11.1.1.4 Definition of Terms

A simulated output spectrum with two tones is shown in Figure 77, with definitions of various terms used in this data sheet.



Device Support (continued)

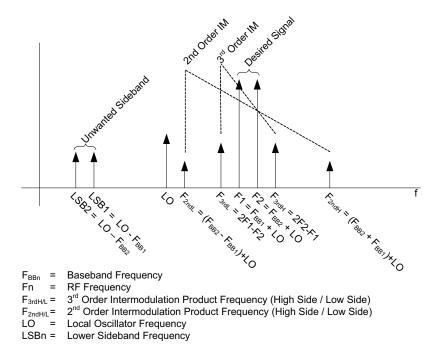


Figure 77. Graphical Illustration of Common Terms

11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.3 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

11.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS | Lead finish/ | MSL rating/ | Op temp (°C) | Part marking |
|-----------------------|--------|---------------|-----------------|-----------------------|------|---------------|---------------------|--------------|-----------------|
| | (1) | (2) | | | (3) | Ball material | Peak reflow | | (6) |
| | | | | | | (4) | (5) | | |
| TRF37T05IRGER | Active | Production | VQFN (RGE) 24 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TR37T05 IRGE |
| TRF37T05IRGER.B | Active | Production | VQFN (RGE) 24 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TR37T05 IRGE |
| TRF37T05IRGET | Active | Production | VQFN (RGE) 24 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TR37T05 IRGE |
| TRF37T05IRGET.B | Active | Production | VQFN (RGE) 24 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TR37T05 IRGE |
| TRF37T05IRGETG4 | Active | Production | VQFN (RGE) 24 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TR37T05 IRGE |
| TRF37T05IRGETG4.B | Active | Production | VQFN (RGE) 24 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TR37T05 IRGE |

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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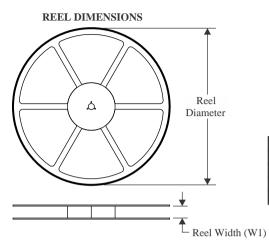
Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

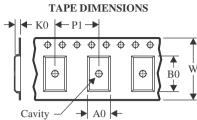
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

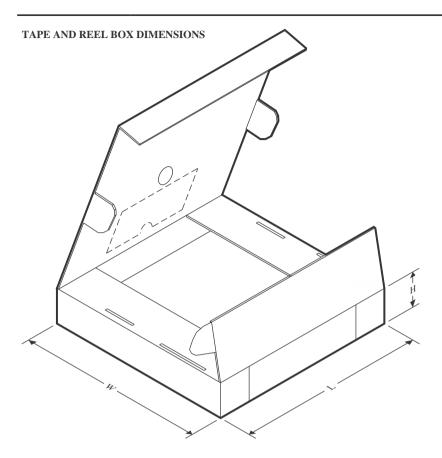
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

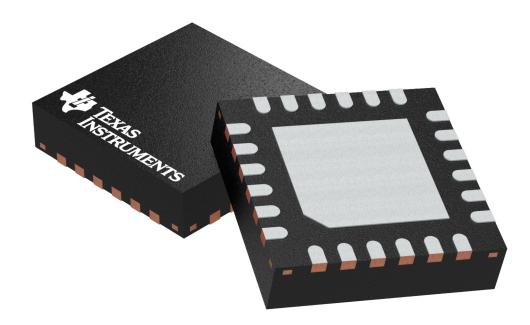
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TRF37T05IRGER | VQFN | RGE | 24 | 3000 | 330.0 | 12.4 | 4.3 | 4.3 | 1.5 | 8.0 | 12.0 | Q2 |
| TRF37T05IRGET | VQFN | RGE | 24 | 250 | 330.0 | 12.4 | 4.3 | 4.3 | 1.5 | 8.0 | 12.0 | Q2 |
| TRF37T05IRGETG4 | VQFN | RGE | 24 | 250 | 330.0 | 12.4 | 4.3 | 4.3 | 1.5 | 8.0 | 12.0 | Q2 |

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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TRF37T05IRGER | VQFN | RGE | 24 | 3000 | 367.0 | 367.0 | 38.0 |
| TRF37T05IRGET | VQFN | RGE | 24 | 250 | 367.0 | 367.0 | 38.0 |
| TRF37T05IRGETG4 | VQFN | RGE | 24 | 250 | 367.0 | 367.0 | 38.0 |

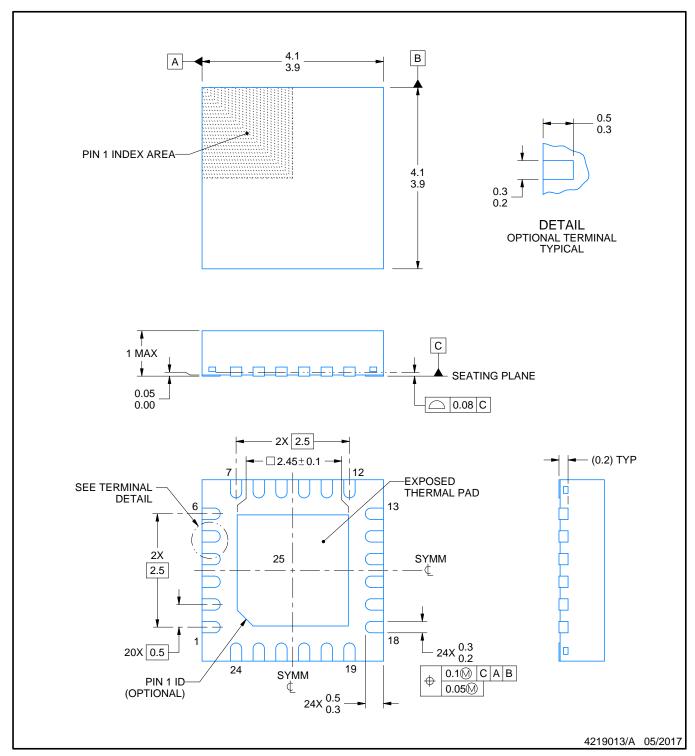


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4204104/H



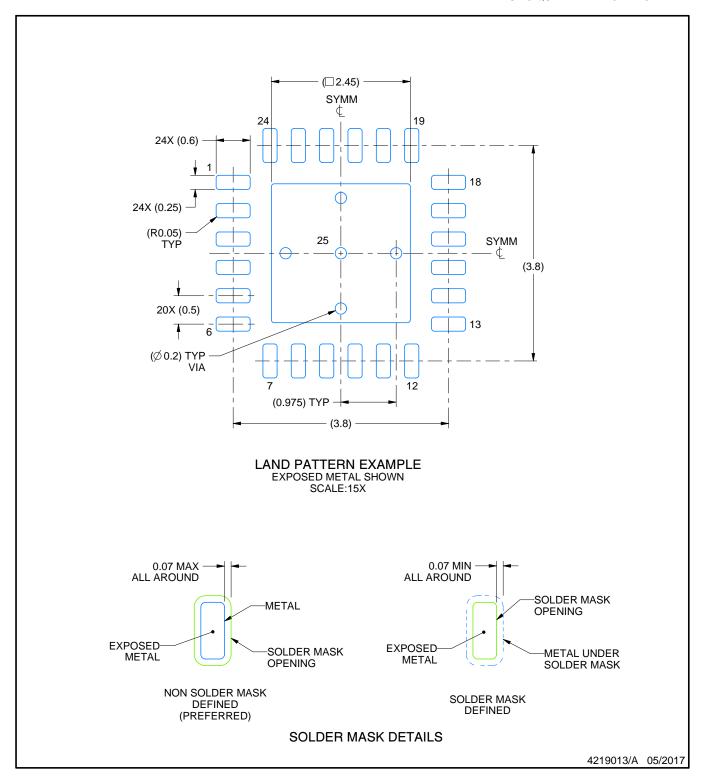




NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

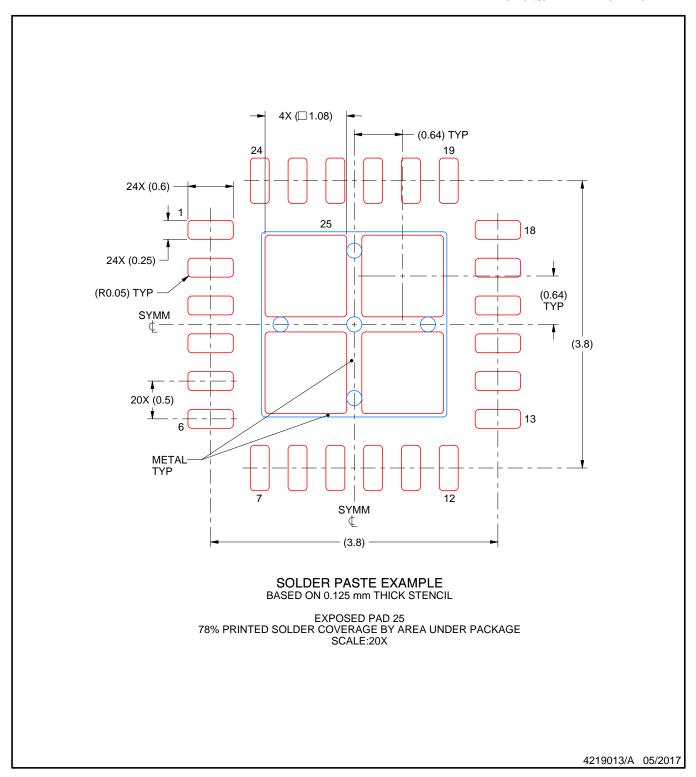




NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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